SN74S1050 12-BIT SCHOTTKY BARRIER DIDDE BUS-TERMINATION ARRAY

SDLS015A D3228, JULY 1989-REVISED MARCH 1990

- Designed to Reduce Reflection Noise
- Repetitive Peak Forward Current . . .
 200 mA
- 12-Bit Array Structure Suited for Bus-Oriented Systems
- ESD Protection Exceeds 10 kV Per MIL-STD-883C, Method 3015
- Package Options Include Plastic "Small Outline" Packages and Standard Plastic 300-mil DIPs

(TOP VIEW) DO1 1 U16 D12 D02 [15 D11 D03 [3 14 D10 13 GND GND □4 12 GND GND [5 11 D09 D04 🛮 6 10 D08 D05 🗆 7 9 D07 D06 🗌 8

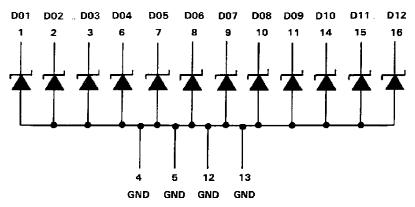
D OR N PACKAGE

description

This Schottky barrier diode bus-termination array is designed to reduce reflection noise on memory bus lines. This device consists of a 12-bit high-speed Schottky diode array suitable for a clamp to GND.

The SN74S1050 is characterized for operation from 0°C to 70°C .

schematic diagram



SN74S1050 12-BIT SCHOTTKY BARRIER DIODE BUS TERMINATION ARRAY

D3228, JULY 1989-REVISED MARCH 1990

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†				
Steady-state reverse voltage, VR				
Continuous forward current, IF: any D terminal from GND				
total through all GND terminals				
Repetitive peak forward current, FRM: any D terminal from GND				
total through all GND terminals				
Continuous total power dissipation at (or below) 25°C free-air temperature 625 mW				
Operating free-air temperature range				
Storage temperature range65 °C to 150 °C				

[†]Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

single-diode operation (see Note 1)

	PARAMETER	TEST CONDITIONS	MIN TYP§	MAX	UNIT
1 _R	Static reverse current	V _R = 7 V		5	μА
۷F	8	ir = 18 mA	0.75	0.95	0.95 1.2
	Static forward voltage	IF = 50 mA	0.95	1.2	
VEM	Peak forward voltage	lp = 200 mA	1.45		٧
	-	$V_R = 0$, $f = 1 MHz$	5	10	pF
Ст	Total capacitance	$V_R = 2 V$, $f = 1 MHz$	4	8	PF

NOTE 1: Test conditions and limits apply separately to each of the diodes. The diodes not under test are open-circuited during the measurement of these characteristics.

multiple-diode operation

ſ	PARAMETER	ER TEST CONDITIONS		TYP§	MAX	UNIT
IX Internal crosstalk current	Total I _F = 1 A, See Note 2		0.6	2	mΑ	
	Total Ic = 198 mA, See Note 2		0.02	0.2	11174	

 $^{^{\}S}$ All typical values are at $T_A = 25$ °C.

NOTE 2. I χ is measured under the following conditions with one diode static and all others switching: Switching diodes: $t_W = 100~\mu s$, duty cycle = 20%; static diode: $V_R = 5~V$. The static diode's input current is the internal crosstalk current $I\chi$.

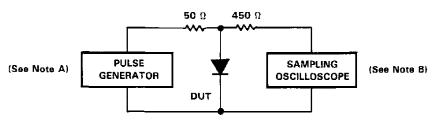
switching characteristics at 25°C free-air temperature (see Figures 1 and 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{rr}	Reverse recovery time	$i_F = 10$ mA, $i_{RM(REC)} = 10$ mA, $i_{R(REC)} = 1$ mA, $R_L = 100 \Omega$		8	16	ns



[‡]These values apply for $t_W \le 100 \mu s$, duty cycle $\le 20\%$.

PARAMETER MEASUREMENT INFORMATION



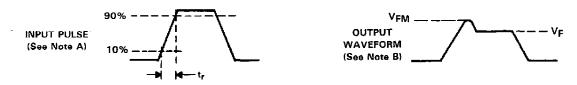


FIGURE 1. FORWARD RECOVERY VOLTAGE

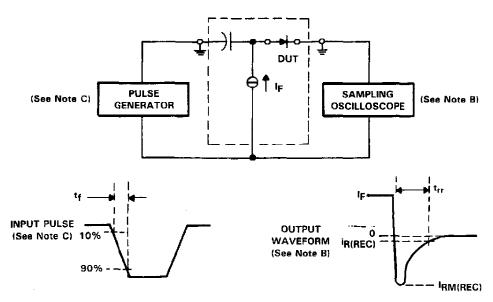


FIGURE 2. REVERSE RECOVERY TIME

NOTES: A. The input pulse is supplied by a pulse generator having the following characteristics: $t_{\Gamma} = 20$ ns, $Z_{OUT} = 50 \Omega$, f = 500 Hz, duty cycle = 0.01.

- B. The output waveform is monitored by an oscilloscope having the following characteristics: $t_f \le 350$ ps. $R_{in} = 50 \Omega$, $C_{in} = \le 5$ pF.
- C. The input pulse is supplied by a pulse generator having the following characteristics: $t_f = 0.5$ ns, $Z_{\text{out}} = 50 \ \Omega$, $t_W = \geq 50$ ns, duty cycle ≤ 0.01 .

APPLICATION INFORMATION

Large negative transients occurring at the inputs of memory devices (DRAMs, SRAMs, EPROMs, etc.), or on the CLOCK lines of many clocked devices can result in improper operation of the device. The SN74S1050 and SN74S1052 diode termination arrays help suppress negative transients caused by transmission line reflections, crosstalk, and switching noise.

Diode terminations have several advantages when compared to resistor termination schemes. Split resistor or Thevenin equivalent termination can cause a substantial increase in power consumption. The use of a single resistor to Ground to terminate a line usually results in degradation of the output high level, resulting in reduced noise immunity. Series damping resistors placed on the outputs of the driver will reduce negative transients, but can also increase propagation delays down the line, as a series resistor reduces the output drive capability of the driving device. Diode terminations have none of these drawbacks.

The operation of the diode arrays in reducing negative transients is explained in the following figures. The diode conducts current whenever the voltage reaches a negative value large enough for the diode to turn on. Suppression of negative transients by the diode tracks the current-voltage characteristic curve for the diode. A typical current-voltage curve for the SN74S1050/S1052 is shown in Figure 3.

To illustrate how the diode arrays act to reduce negative transients at the end of a transmission line, the test setup in Figure 4 was evaluated. The resulting waveforms with and without the diode are shown in Figure 5.

The maximum effectiveness of the diode in suppressing negative transients occurs when they are placed at the end of a line and/or the end of a long stub branching off a main transmission line. The diodes can also be used to reduce the negative transients that occur due to discontinuities in the middle of a line. An example of this is a slot in a backplane that is provided for an add-on card.

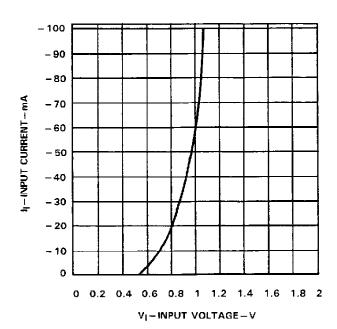


FIGURE 3. TYPICAL CURRENT-VOLTAGE CURVE

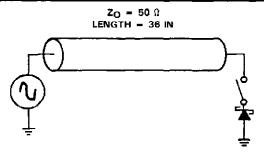


FIGURE 4. DIODE TEST SETUP

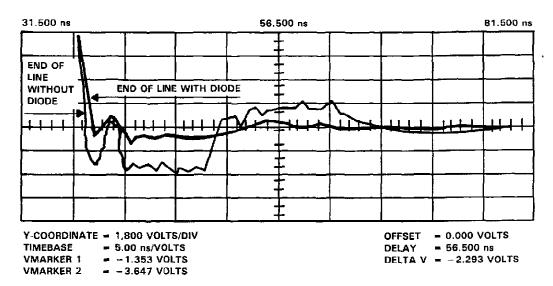


FIGURE 5. SCOPE DISPLAY

IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated